

# **Diode Chip**

**DWPJ29-16** 

tentative

## Circuit Diagram



### **Product Summary**

Characteristics	Value	Unit
$V_{RRM}$	1600	V
I F <sub>(AV)</sub>	48	Α
Chip Dimensions	5,4x5,4	mm
unsawn wafer	Yes	
sawn on foil	Yes	
in waffle pack	Yes	

## **Applications**

- DC Power Supplies
- Field Supply for DC motors
- Battery DC Power Supplies
- Power Rectifiers

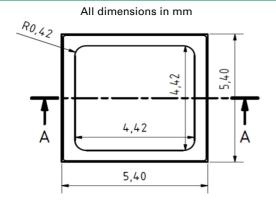
#### **Features**

- glassivation • Tvjm =
- · advanced planar technology
- 150°C
- soft recovery rectifier diode
- high commutation robustness
- anode top

#### **Mechanical Characteristic**

Characteristic		Conditions	Value	Unit
Area active			20,10	mm²
Area total			29,16	mm²
Thickness			265	μm
Wafer size Ø			150	mm
Die Per Wafer			471	
Material			Si	
Passivation front side			Glass	
Metalisation front side		bondable:	Al	
Metalisation back side		solderable (only):	Al/Ti/NiV/Ag	
Recom. wire bonds (AI)	Anode	Number	5	
*= stitch bonds		Ø	380	μm
Reject ink dot size		Ø	0.4 - 1.0	mm
Recom. solder temp.			<300	°C
Recom. Storage environment	sawn on foil	in org. container, in dry nitrogen	<6	month
	unsawn wafer	in org. container, in dry nitrogen	<2	year
	in waffle pack	in org. container, in dry nitrogen	<2	year
Storage temp.			-4040	°C

#### **Dimensions**



Passivation Anode (metal) Cathode (metal)

Specifications are subject to change without notice

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## **Electrical Parameters**

Cymhol	Conditions		Value			11	
Symbol		Conditions			Тур	Max	Unit
Static Characteris	tics						
$V_R$	$V = V_{RRM}$	T	vj = 25°C			1600	V
$I_R$	$V = V_{RRM}$		vj = 25°C			50	μA
			vj = 150°C			0,5	mA
$V_F$	If = 60A		vj = 25°C		1,10	1,20	V
•			vj = 150°C		1,04		V
$V_{F0}$	For power loss		-			0,90	V
r <sub>F</sub>	·	T.	vj = 150°C			4,2	mΩ
$\overline{T}_{VJ}$			•	-40		150	°C
Ι <sub>Γ(ΑV)</sub> *	DC	Т	c = 100°C		48		Α
R <sub>thJC</sub> *	DC current					0,8	K/W
I <sub>FSM</sub>	Tvj = 45 °C	t = 10 ms	(50) Hz , sine			640	Α
	$V_R = 0 V$	t = 8.3  ms	(60) Hz , sine			680	Α
	Tvj = 150 °C	t = 10 ms	(50) Hz , sine			550	Α
	$V_R = 0 V$	t = 8.3  ms	(60) Hz , sine			580	Α
<i>l</i> ²t	Tvj = 45 °C	t = 10 ms	(50) Hz , sine			2000	A <sup>2</sup> s
	$V_R = 0 V$	t = 8.3  ms	(60) Hz , sine			1900	A <sup>2</sup> s
	Tvj = 150 °C	t = 10 ms	(50) Hz , sine			1500	A <sup>2</sup> s
	$V_R = 0 V$	t = 8.3  ms	(60) Hz , sine			1300	A <sup>2</sup> s

<sup>\*</sup> Data according to assembled 380 $\mu$ m DCB

Data according to IEC 60747

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